

General Description

The MY8N65D can be used in various power switching circuit for system miniaturization and higher efficiency.

The package form is TO-252-2L, which accords with the RoHS standard

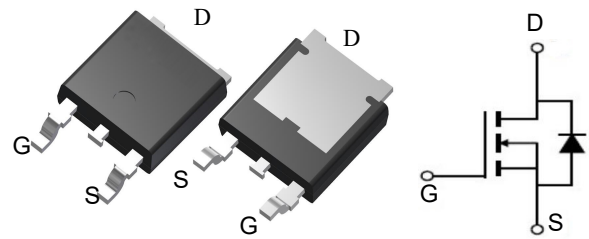


Features

V_{DSS}	650	V
I_D	8	A
$P_D(T_C=25^\circ C)$	48	W
$R_{DS(ON)}(at V_{GS}=10V)$	100	$m\Omega$

Application

- Fast Switching
- Low ON Resistance
- Low Gate Charge
- Power factor correction



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY8N65D	TO-252	MY8N65D	2500

Absolute Maximum Ratings ($T_C=25^\circ C$ unless otherwise noted)

Symbol	Parameters	Ratings	Unit
V_{DSS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage-Continuous	± 30	V
I_D	Drain Current-Continuous (Note 2)	8	A
I_{DM}	Drain Current-Single Plused (Note 1)	52	A
P_D	Power Dissipation (Note 2)	48	W
T_j	Max.Operating junction temperature	150	$^\circ C/W$

Electrical Characteristics ($T_c=25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Symbol	Parameters	Min	Typ	Max	Units	Conditions
Static Characteristics						
B _{VDS}	Drain-Source Breakdown VoltageCurrent (Note 1)	600	--	--	mA	I _D =250μA V _{GS} =0V , T _J =25°C
V _{GS(th)}	Gate Threshold Voltage	2.0	--	4.0	V	V _{DS} =V _{GS} , I _D =250μA
R _{DS(on)}	Drain-Source On-Resistance	--	100	120	mΩ	V _{GS} =10V , I _D =4A
I _{GSS}	Gate-Body Leakage Current	--	--	±100	nA	V _{GS} =±30V , V _{DS} =0
I _{DSS}	Zero Gate Voltage Drain Current	--	--	1	μA	V _{DS} =650V , V _{GS} =0
Switching Characteristics						
T _{d (on)}	Turn-On Delay Time	--	16.5	45	ns	V _{DS} =325V , I _D =8A, R _G =25Ω (Note 2)
T _r	Rise Time	--	60.5	130	ns	
T _{d (off)}	Turn-Off Delay Time	--	81	170	ns	
T _f	Fall Time	--	64.5	140	ns	
Q _g	Total Gate Charge	--	28	36	nC	V _{DS} =480 , V _{GS} =1 , I _D =8A (Note 2)
Q _{gs}	Gate-Source Charge	--	4.5	--	nC	
Q _{gd}	Gate-Drain Charge	--	12	--	nC	
Dynamic Characteristics						
C _{iss}	Input Capacitance	--	965	1255	pF	V _{DS} =25V , V _{GS} =0, f=1MHz
C _{oss}	Output Capacitance	--	105	135	pF	
C _{rss}	Reverse Transfer Capacitance	--	12	16	pF	
I _s	Continuous Drain-Source Diode ForwardCurrent (Note 2)	--	--	8	A	
V _{SD}	Diode Forward On-Voltage	--	--	1.4	V	I _S =8A , V _{GS} =0
R _{th(j-c)}	Thermal Resistance, Junction to Case	--	--	2.6	C/ W	

Note 1: Repetitive Rating : Pulse width limited by maximum junction temperature

Note 2: Pulse test: $PW \leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

Typical Characteristics

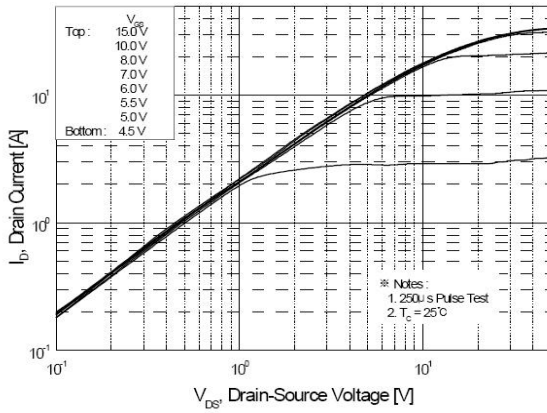


Figure 1. On-Region Characteristics

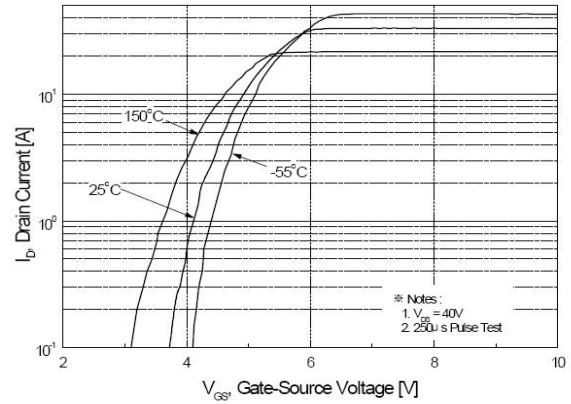


Figure 2. Transfer Characteristics

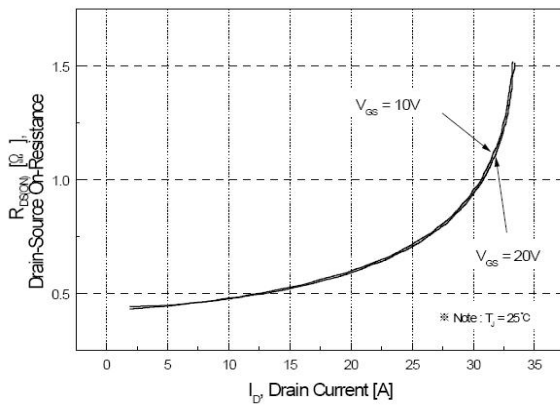


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

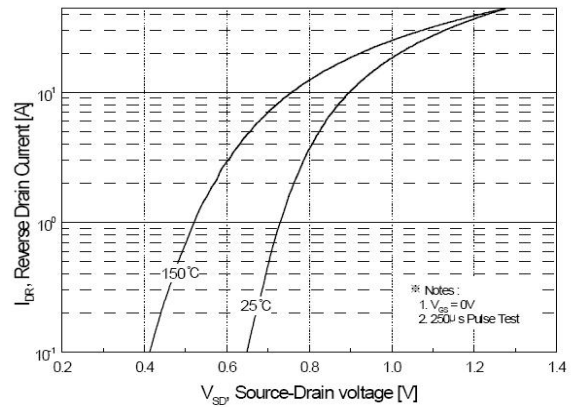


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

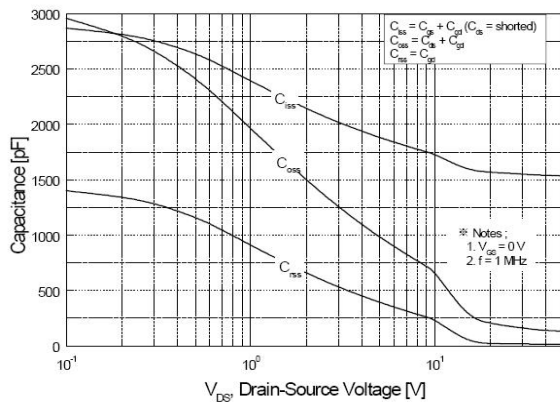


Figure 5. Capacitance Characteristics

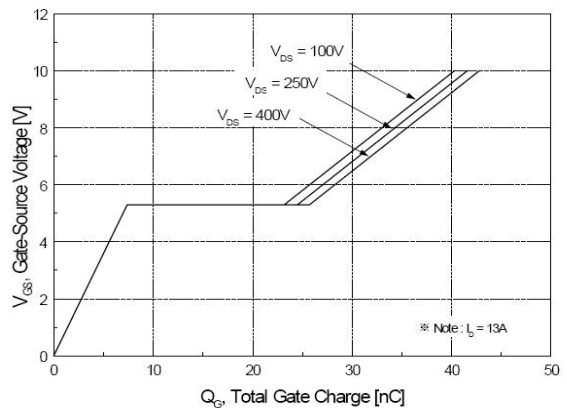


Figure 6. Gate Charge Characteristics

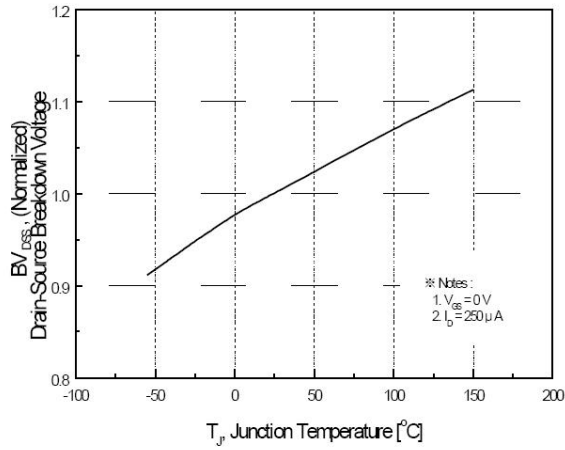


Figure 7. Breakdown Voltage Variation vs Temperature

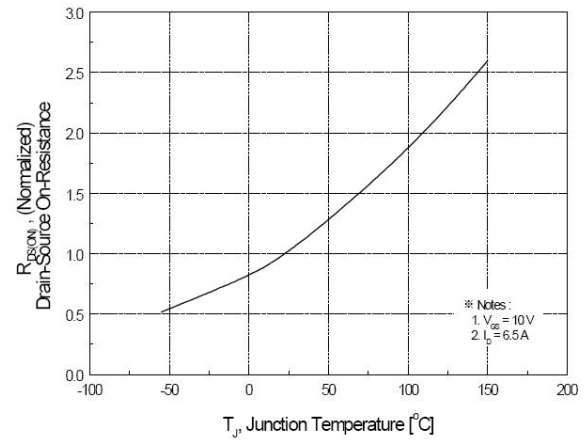


Figure 8. On-Resistance Variation vs Temperature

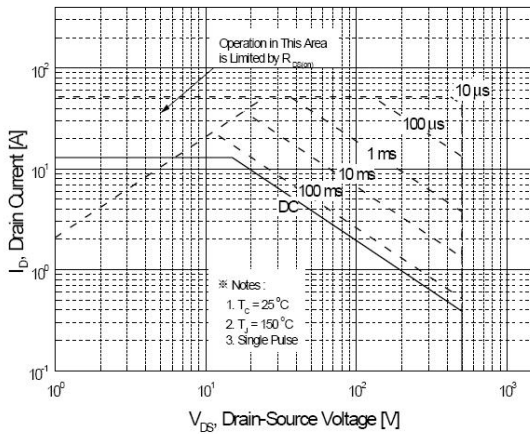


Figure 9. Maximum Safe Operating Area

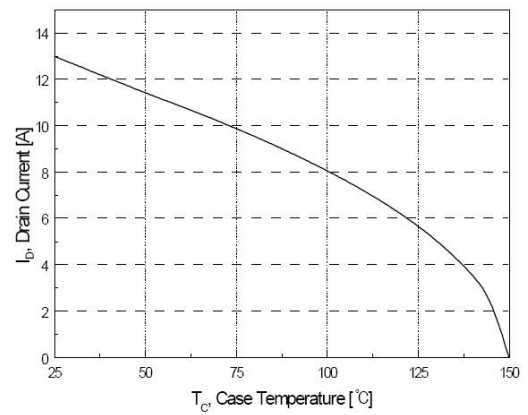


Figure 10. Maximum Drain Current vs Case Temperature

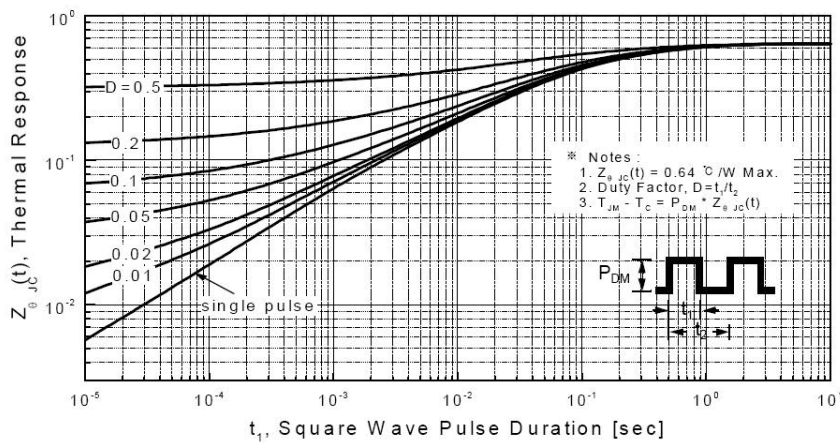


Figure 11. Transient Thermal Response Curve

Fig 12. Gate Charge Test Circuit & Waveform

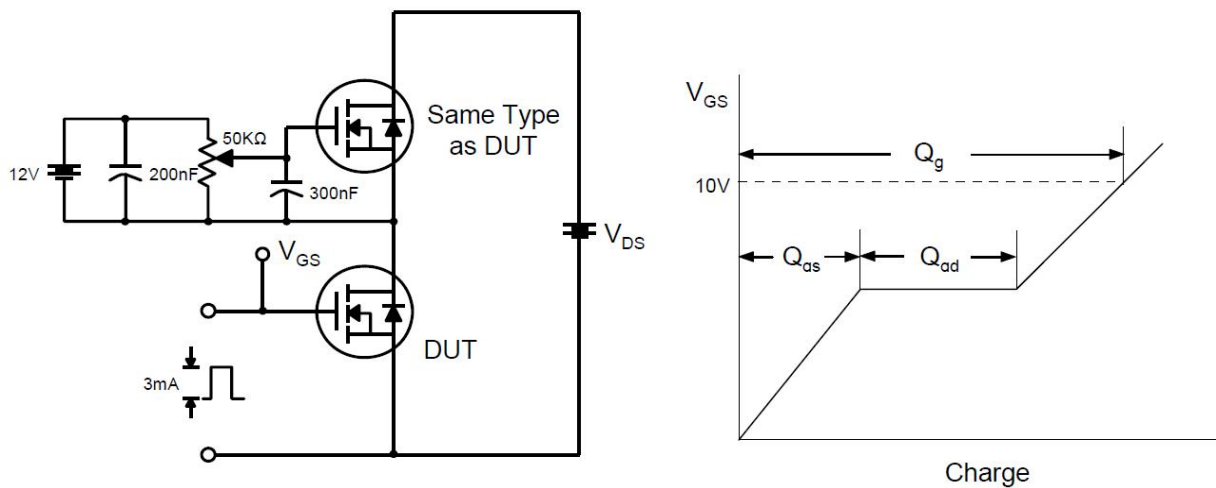


Fig 13. Resistive Switching Test Circuit & Waveforms

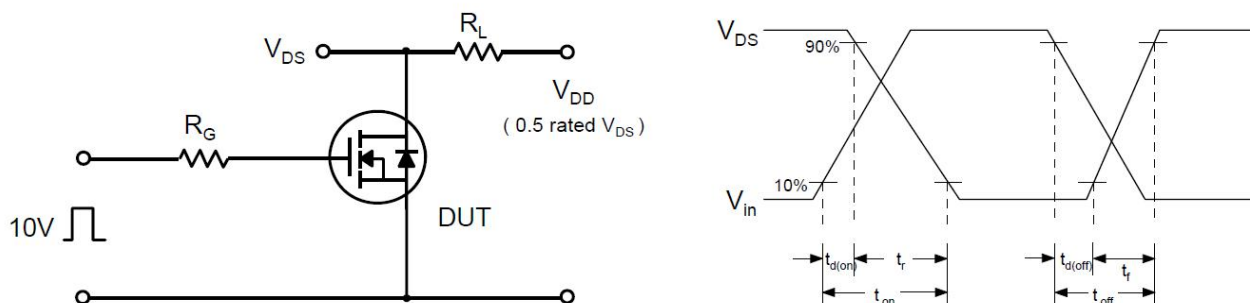


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

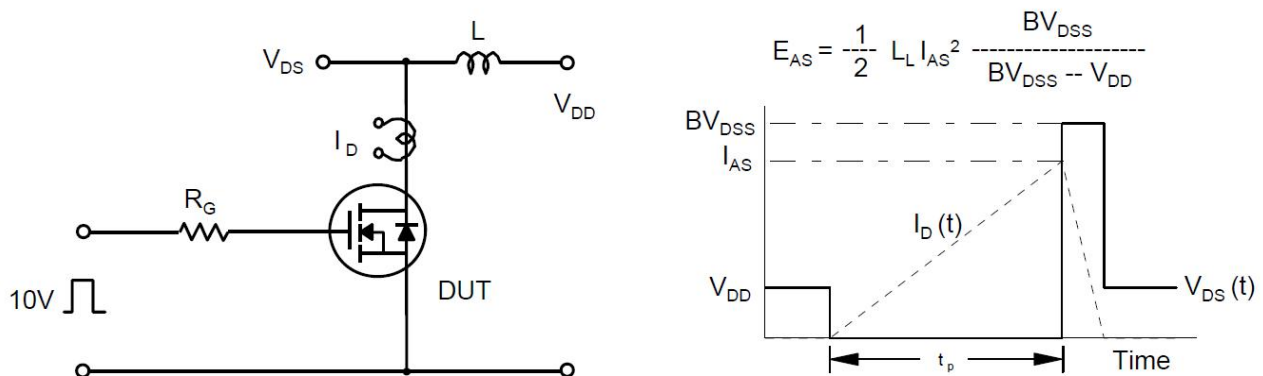
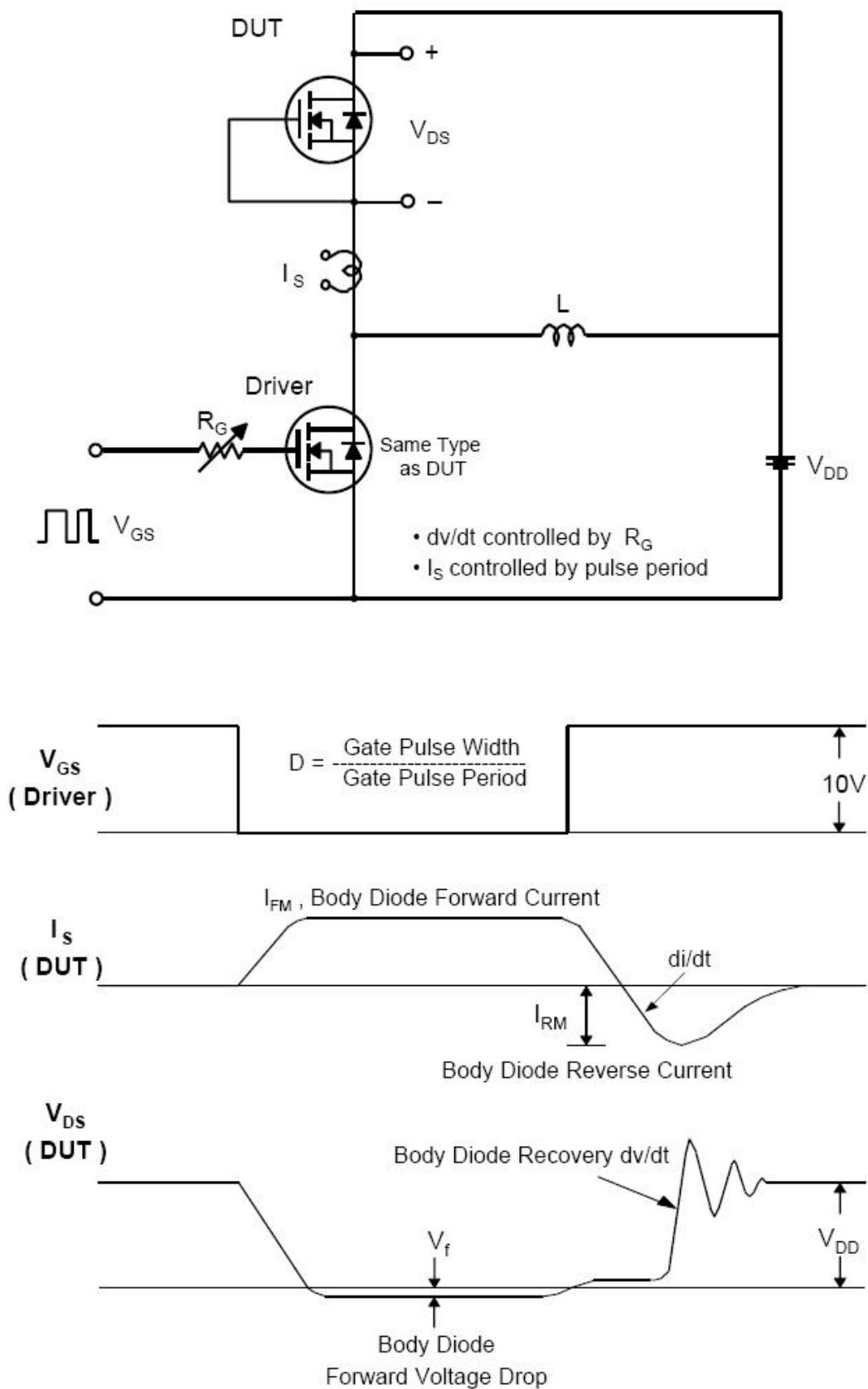
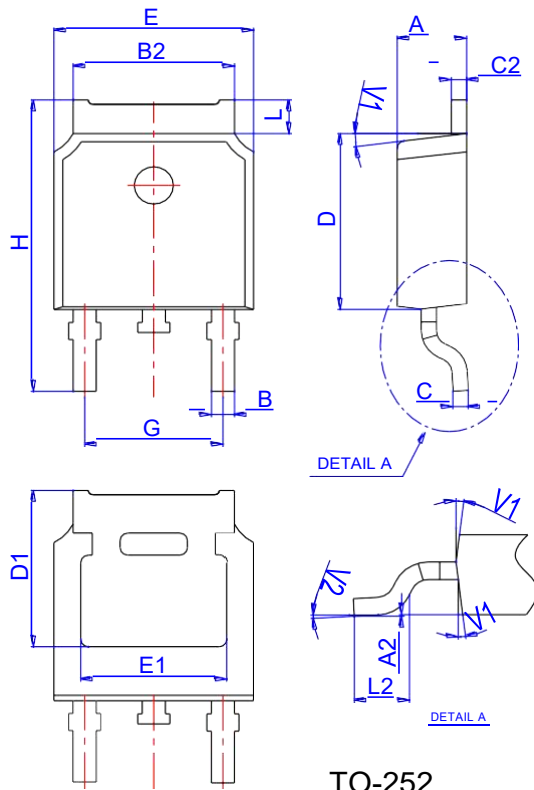


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



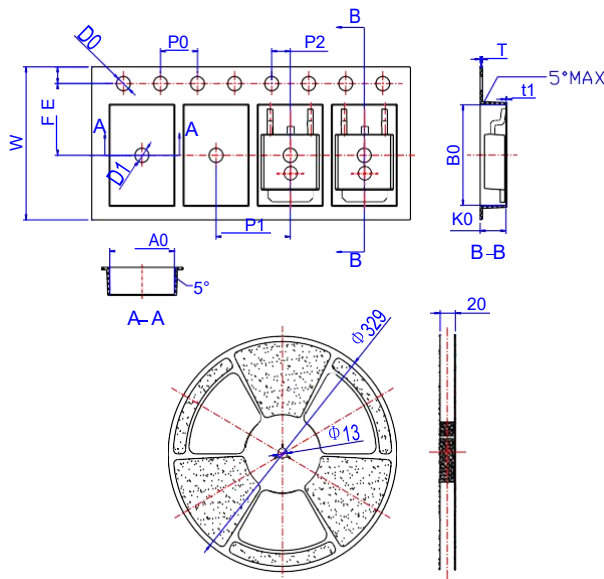
Package Mechanical Data-TO-252-JQ Single



TO-252

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Specification-TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583